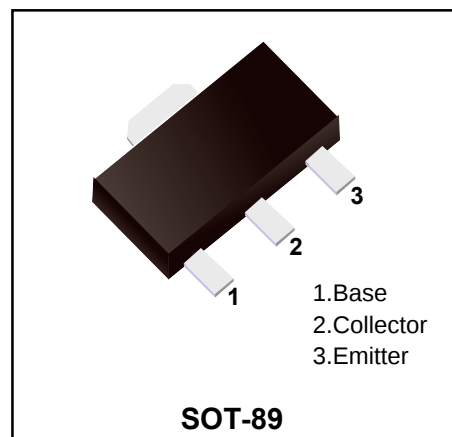


NPN TRANSISTOR

FEATURES

- ◆High breakdown voltage
- ◆Low collector-emitter saturation voltage
- ◆Complementary to MPSA92SI (PNP)



Marking Code

MMBTA42SI

A42

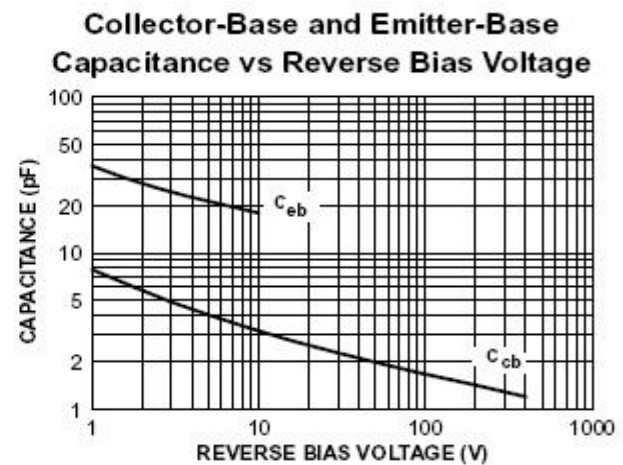
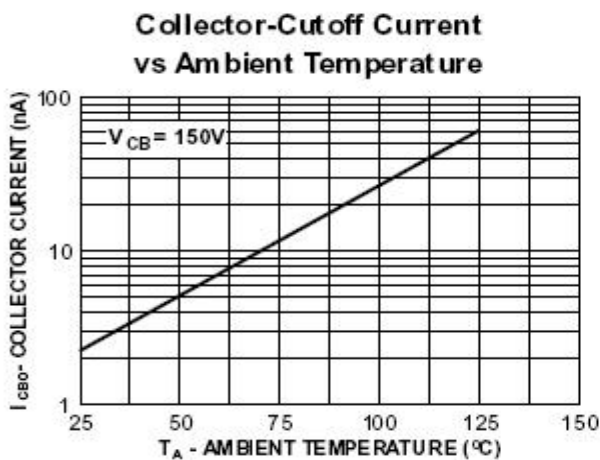
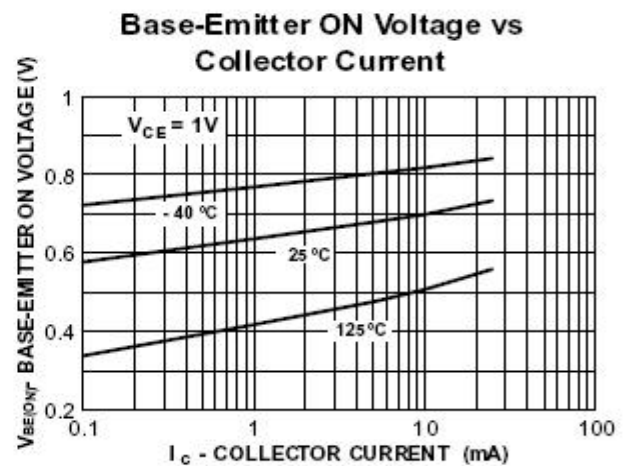
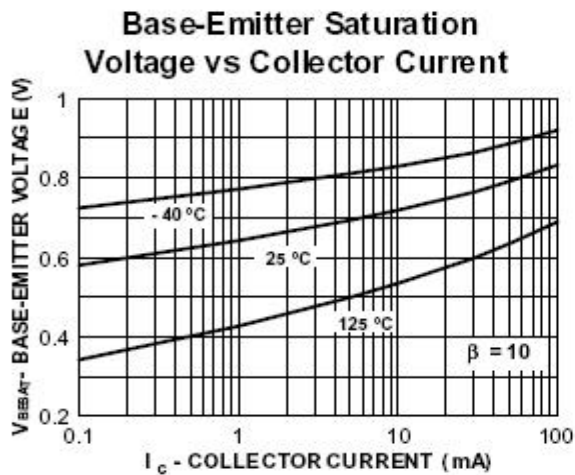
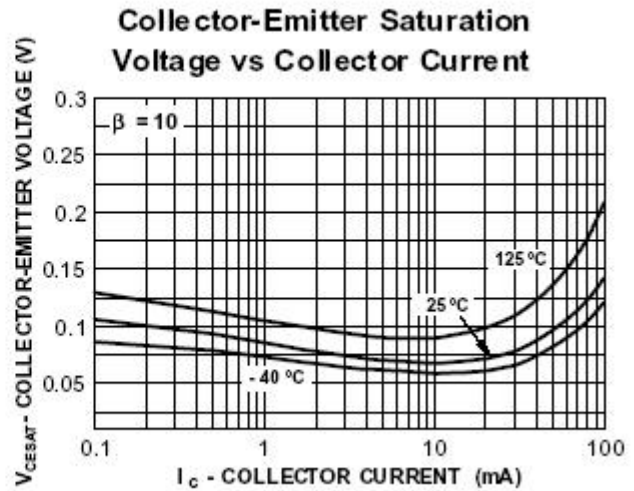
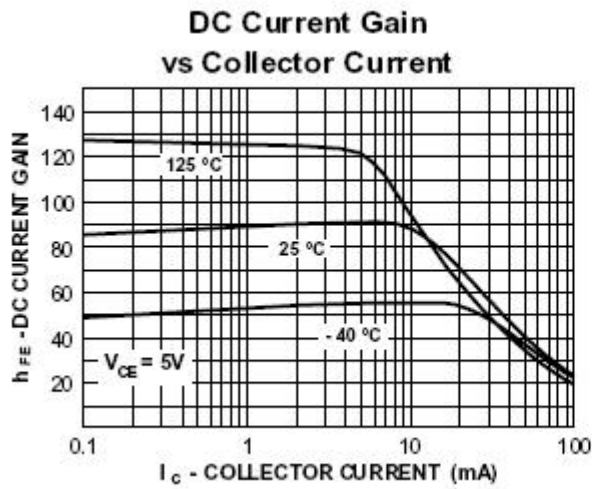
MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Characteristics	Symbols	Value	Units
Collector-Base Voltage	V_{CBO}	300	V
Collector-Emitter Voltage	V_{CEO}	300	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current -Continuous	I_C	0.3	A
Collector Power dissipation	P_C	0.35	W
Thermal Resistance, junction to Ambient	$R_{\theta JA}$	357	°C/mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Characteristics	Test Condition	Symbols	Min	Typ	Max	Units
Collector-base breakdown voltage	$I_C = 100\mu A, I_E = 0$	$V_{(BR)CBO}$	300	-	-	V
Collector-emitter breakdown voltage	$I_C = 1mA, I_B = 0$	$V_{(BR)CEO}$	300	-	-	V
Emitter-base breakdown voltage	$I_E = 100\mu A, I_C = 0$	$V_{(BR)EBO}$	5	-	-	V
Collector cut-off current	$V_{CB} = 200V, I_E = 0$	I_{CBO}	-	-	0.25	μA
Emitter cut-off current	$V_{EB} = 5V, I_C = 0$	I_{EBO}	-	-	0.1	μA
DC current gain	$V_{CE} = 10V, I_C = 1mA$	$h_{FE(1)}$	60	-	-	
	$V_{CE} = 10V, I_C = 10mA$	$h_{FE(2)}$	100	-	200	
	$V_{CE} = 10V, I_C = 30mA$	$h_{FE(3)}$	60	-	-	
Collector-emitter saturation voltage	$I_C = 20mA, I_B = 2mA$	$V_{CE(sat)}$	-	-	0.2	V
Base-emitter saturation voltage	$I_C = 20mA, I_B = 2mA$	$V_{BE(sat)}$	-	-	0.9	V
Transition frequency	$V_{CE} = 20V, I_C = 10mA, f = 30MHz$	f_T	50	-	-	MHz

Typical Characteristics



Ordering information

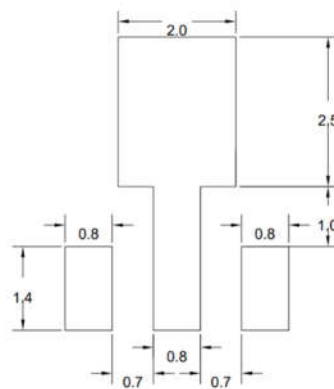
Package	Packing Description	Base Quantity	Packing Quantity
SOT-89	Tape/Reel, 7" reel	1000pcs/Reel	6000PCS/Box 30000PCS/Carton

Package Dimensions

SOT-89

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	1.40	1.60	0.055	0.063
b	0.32	0.52	0.013	0.020
b1	0.38	0.58	0.015	0.023
c	0.35	0.45	0.014	0.018
D	4.40	4.60	0.173	0.181
D1	1.45	1.65	0.057	0.065
D2	1.70	1.80	0.067	0.071
E	2.30	2.60	0.091	0.102
E1	3.95	4.25	0.156	0.167
E2	1.80	2.00	0.071	0.079
e	1.40	1.60	0.055	0.063
e1	2.80	3.20	0.110	0.126
L	0.90	1.20	0.035	0.047

The recommended mounting pad size



UNIT:MM

Disclaimer

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